Diode Semiconductor Device - Page 1 of 1



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nclosure Material:
Blass
overall Length:
.375 inches
erminal Length:
.250 inches
overall Diameter:
.220 inches
Iounting Method:
erminal
eatures Provided:
lermetically sealed case
emiconductor Material:
ilicon
urrent Rating Per Characteristic:
50.00 milliamperes forward current, average absolute
laximum Operating Tempurature Per Measurement Point
75.0 degrees celsius ambient air
erminal Type And Quantity:
uninsulated wire lead
helf Life:
l/a
nit Of Measure:
emilitarization:
lo
iig:
110a0